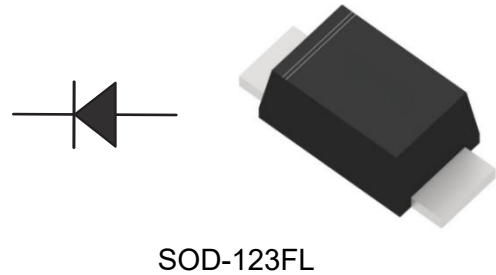


### Surface Mount UltraFast Recovery Rectifiers

Parameter	Value	Unit
$V_{RRM}$	50~1000	V
$I_{F(AV)}$	1.0	A



#### Features

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- High efficiency

#### Applications

- For use in high-frequency rectification and free-wheeling applications in switching-mode converters and inverters for consumer electronics, computer systems, and telecommunications.

#### Absolute Maximum Ratings and Characteristics (at $T_J = 25^\circ\text{C}$ unless otherwise specified)

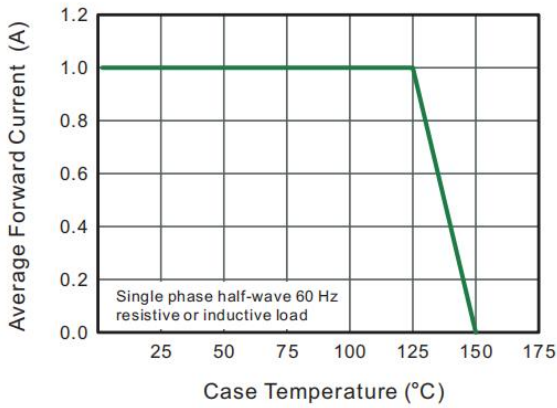
Parameter	Symbol	U1A	U1B	U1D	U1G	U1J	U1K	U1M	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_c = 125^\circ\text{C}$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load	$I_{FSM}$	30							A
Maximum Instantaneous Forward Voltage at 1A	$V_F$	1.0		1.3		1.65		V	
Maximum DC Reverse Current at Rated DC Blocking Voltage	$I_R$	5 100							$\mu\text{A}$
Maximum Reverse Recovery Time ( 1 )	$t_{rr}$	50				75			ns
Typical Junction Capacitance ( 2 )	$C_j$	15							pF
Typical Thermal Resistance ( 3 )	$R_{\theta JA}$	85							$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150							$^\circ\text{C}$

#### Notes:

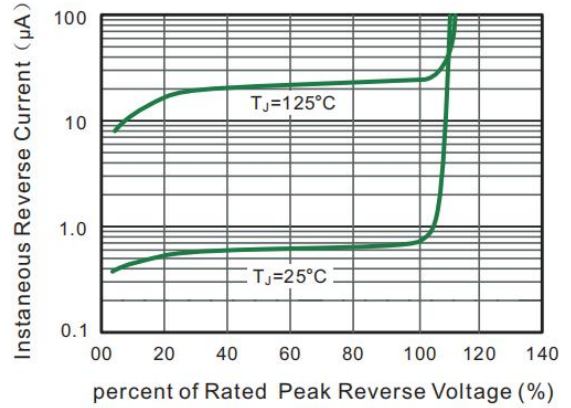
- ( 1 ) Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .
- ( 2 ) Measured at 1 MHz and applied reverse voltage of 4 VD.C
- ( 3 ) P.C. B . mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas .

**Typical characteristics**

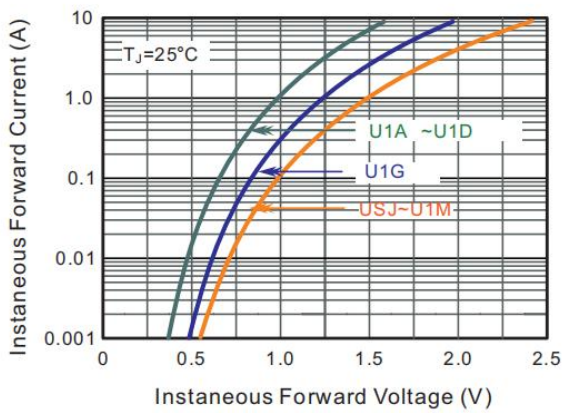
**Fig.1 Forward Current Derating Curve**



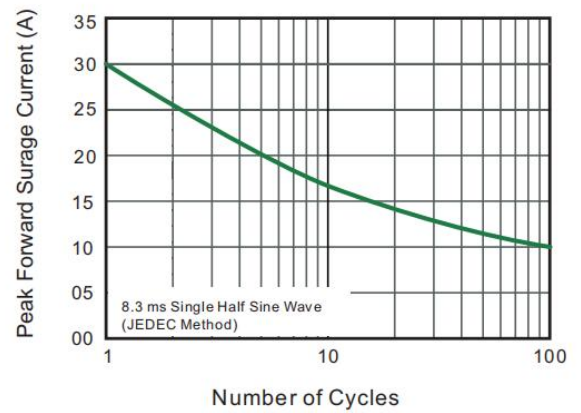
**Fig.2 Typical Reverse Characteristics**



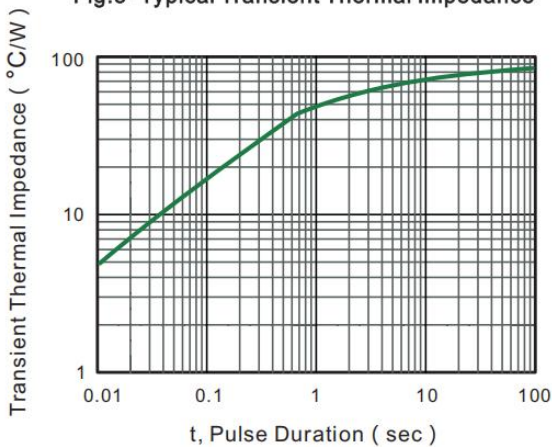
**Fig.3 Typical Forward Characteristics**



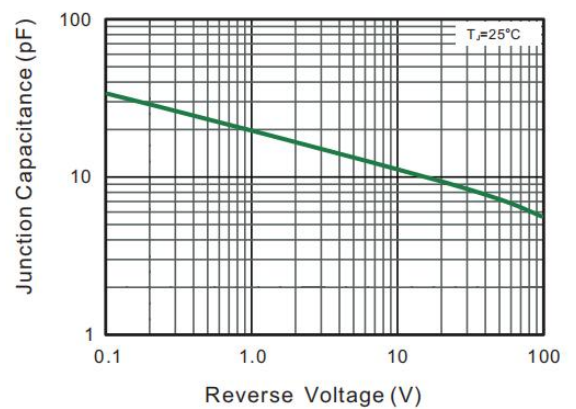
**Fig.4 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.5- Typical Transient Thermal Impedance**



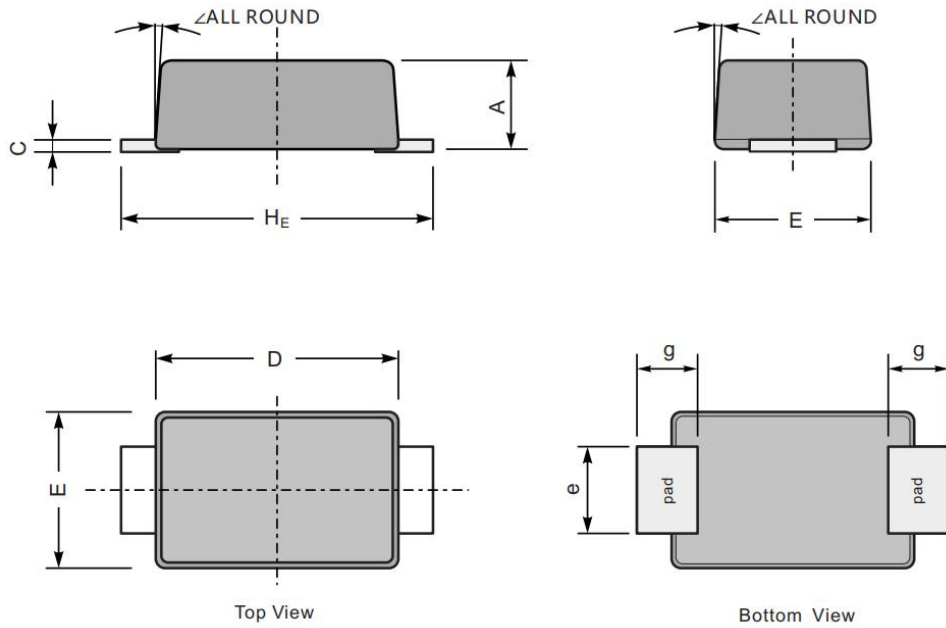
**Fig.6 Typical Junction Capacitance**



### Package Outlines

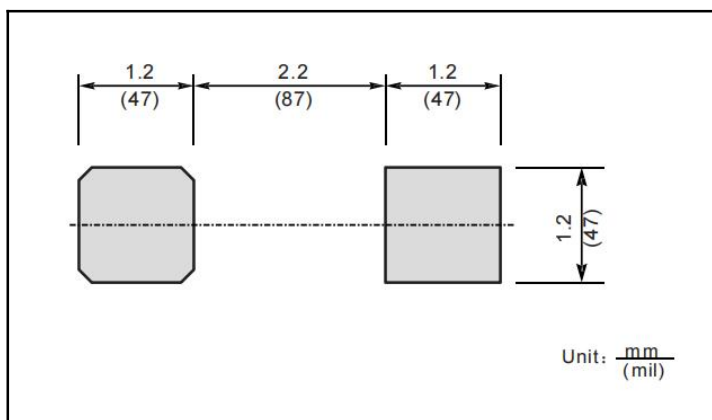
Plastic surface mounted package; 2 leads

#### SOD-123FL



UNIT		A	C	D	E	e	g	$H_E$	$\angle$
mm	max	1.15	0.20	2.9	1.9	1.2	0.9	3.8	5°
	min	0.95	0.12	2.6	1.7	0.9	0.7	3.5	
mil	max	45	7.9	114	75	47	35	150	
	min	37	4.7	102	67	35	28	138	

### The recommended mounting pad size



### Marking

Type number	Marking code
U1A	U1A
U1B	U1B
U1D	U1D
U1G	U1G
U1J	U1J
U1K	U1K
U1M	U1M

**\*Important Usage Information and Disclaimer**

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